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Kind regards,

Team Nexperia

PEMD30; PUMD30

NPN/PNP double resistor-equipped transistors;
R1 = 2.2 k Ω , R2 = open

Rev. 01 — 31 March 2006

Product data sheet

1. Product profile

1.1 General description

NPN/PNP double Resistor-Equipped Transistors (RET) in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

| Type number | Package | | PNP/PNP complement | NPN/PNP complement |
|-------------|---------|-------|--------------------|--------------------|
| | Philips | JEITA | | |
| PEMD30 | SOT666 | - | PEMB30 | PEMH30 |
| PUMD30 | SOT363 | SC-88 | PUMB30 | PUMH30 |

1.2 Features

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- Low current peripheral driver
- Control of IC inputs
- Cost-saving alternative for BC847BPN and BC847BVN
- Switching loads

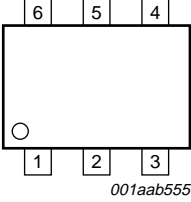
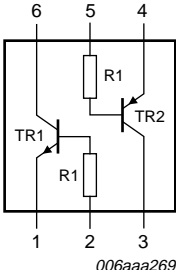
1.4 Quick reference data

Table 2. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|---------------------------|------------|------|-----|------|------------|
| Per transistor; for the PNP transistor with negative polarity | | | | | | |
| V _{CEO} | collector-emitter voltage | open base | - | - | 50 | V |
| I _O | output current | | - | - | 100 | mA |
| R1 | bias resistor 1 (input) | | 1.54 | 2.2 | 2.86 | k Ω |

2. Pinning information

Table 3. Pinning

| Pin | Description | Simplified outline | Symbol |
|-----|------------------------|---|---|
| 1 | GND (emitter) TR1 |  |  |
| 2 | input (base) TR1 | | |
| 3 | output (collector) TR2 | | |
| 4 | GND (emitter) TR2 | | |
| 5 | input (base) TR2 | | |
| 6 | output (collector) TR1 | | |

3. Ordering information

Table 4. Ordering information

| Type number | Package | | Version |
|-------------|---------|--|---------|
| | Name | Description | |
| PEMD30 | - | plastic surface-mounted package; 6 leads | SOT666 |
| PUMD30 | SC-88 | plastic surface-mounted package; 6 leads | SOT363 |

4. Marking

Table 5. Marking codes

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| PEMD30 | 2U |
| PUMD30 | *B3 |

- [1] * = -: made in Hong Kong
 * = p: made in Hong Kong
 * = t: made in Malaysia
 * = W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit | |
|--|---------------------------|--|--------|------|------|----|
| Per transistor; for the PNP transistor with negative polarity | | | | | | |
| V _{CBO} | collector-base voltage | open emitter | - | 50 | V | |
| V _{CEO} | collector-emitter voltage | open base | - | 50 | V | |
| V _{EBO} | emitter-base voltage | open collector | - | 5 | V | |
| I _O | output current | | - | 100 | mA | |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | - | 100 | mA | |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | | | | |
| | SOT363 | | [1] | - | 200 | mW |
| | SOT666 | | [1][2] | - | 200 | mW |
| Per device | | | | | | |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | | | | |
| | SOT363 | | [1] | - | 300 | mW |
| | SOT666 | | [1][2] | - | 300 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C | |
| T _j | junction temperature | | - | 150 | °C | |
| T _{amb} | ambient temperature | | -65 | +150 | °C | |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

6. Thermal characteristics

Table 7. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|-----------------------|---|-------------|--------|-----|-----|------|-----|
| Per transistor | | | | | | | |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | | | | | |
| | SOT363 | | [1] | - | - | 625 | K/W |
| | SOT666 | | [1][2] | - | - | 625 | K/W |
| Per device | | | | | | | |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | | | | | |
| | SOT363 | | [1] | - | - | 416 | K/W |
| | SOT666 | | [1][2] | - | - | 416 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

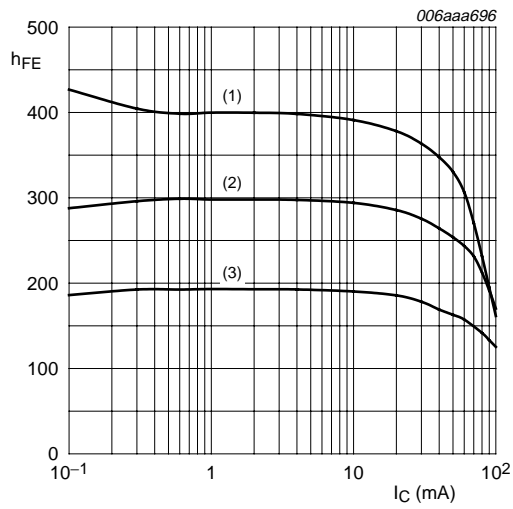
[2] Reflow soldering is the only recommended soldering method.

7. Characteristics

Table 8. Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

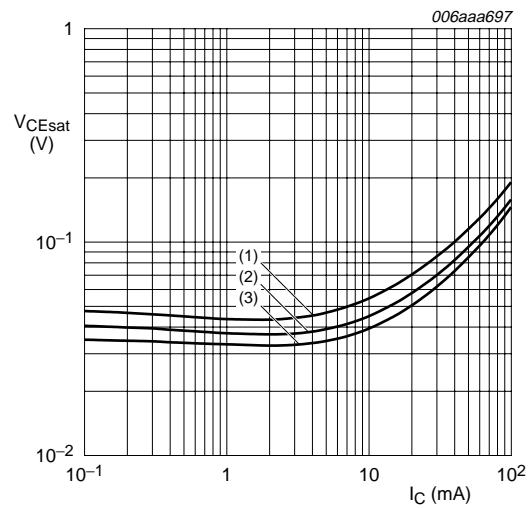
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|--------------------------------------|---|------|-----|------|---------------|
| Per transistor; for the PNP transistor with negative polarity | | | | | | |
| I_{CBO} | collector-base cut-off current | $V_{CB} = 50\text{ V}; I_E = 0\text{ A}$ | - | - | 100 | nA |
| I_{CEO} | collector-emitter cut-off current | $V_{CE} = 30\text{ V}; I_B = 0\text{ A}$ | - | - | 1 | μA |
| | | $V_{CE} = 30\text{ V}; I_B = 0\text{ A}; T_j = 150\text{ }^{\circ}\text{C}$ | - | - | 50 | μA |
| I_{EBO} | emitter-base cut-off current | $V_{EB} = 5\text{ V}; I_C = 0\text{ A}$ | - | - | 100 | nA |
| h_{FE} | DC current gain | $V_{CE} = 5\text{ V}; I_C = 20\text{ mA}$ | 30 | - | - | |
| V_{CEsat} | collector-emitter saturation voltage | $I_C = 10\text{ mA}; I_B = 0.5\text{ mA}$ | - | - | 150 | mV |
| R1 | bias resistor 1 (input) | | 1.54 | 2.2 | 2.86 | k Ω |
| C_c | collector capacitance | $V_{CB} = 10\text{ V}; I_E = i_e = 0\text{ A}; f = 1\text{ MHz}$ | | | | |
| | | TR1 (NPN) | - | - | 2.5 | pF |
| | | TR2 (PNP) | - | - | 3 | pF |



$V_{CE} = 5 \text{ V}$

- (1) $T_{amb} = 100 \text{ }^\circ\text{C}$
- (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
- (3) $T_{amb} = -40 \text{ }^\circ\text{C}$

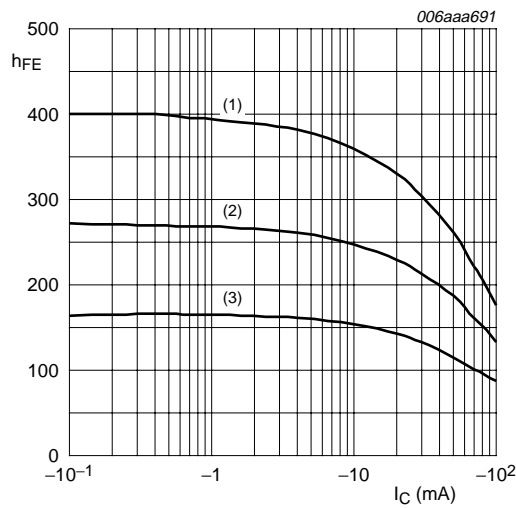
Fig 1. TR1 (NPN): DC current gain as a function of collector current; typical values



$I_C/I_B = 20$

- (1) $T_{amb} = 100 \text{ }^\circ\text{C}$
- (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
- (3) $T_{amb} = -40 \text{ }^\circ\text{C}$

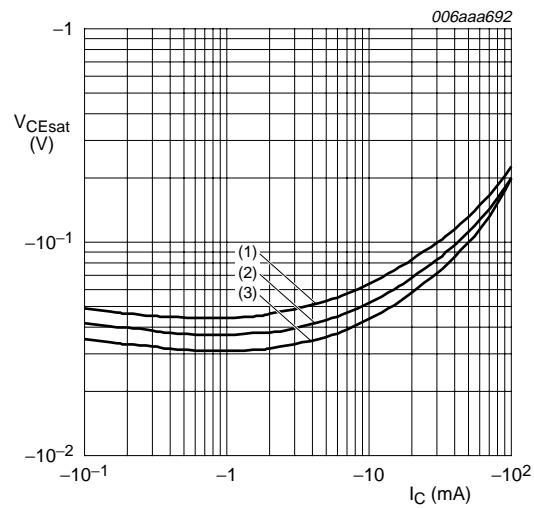
Fig 2. TR1 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values



$V_{CE} = -5 \text{ V}$

- (1) $T_{amb} = 100 \text{ }^\circ\text{C}$
- (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
- (3) $T_{amb} = -40 \text{ }^\circ\text{C}$

Fig 3. TR2 (PNP): DC current gain as a function of collector current; typical values



$I_C/I_B = 20$

- (1) $T_{amb} = 100 \text{ }^\circ\text{C}$
- (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
- (3) $T_{amb} = -40 \text{ }^\circ\text{C}$

Fig 4. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values

8. Package outline

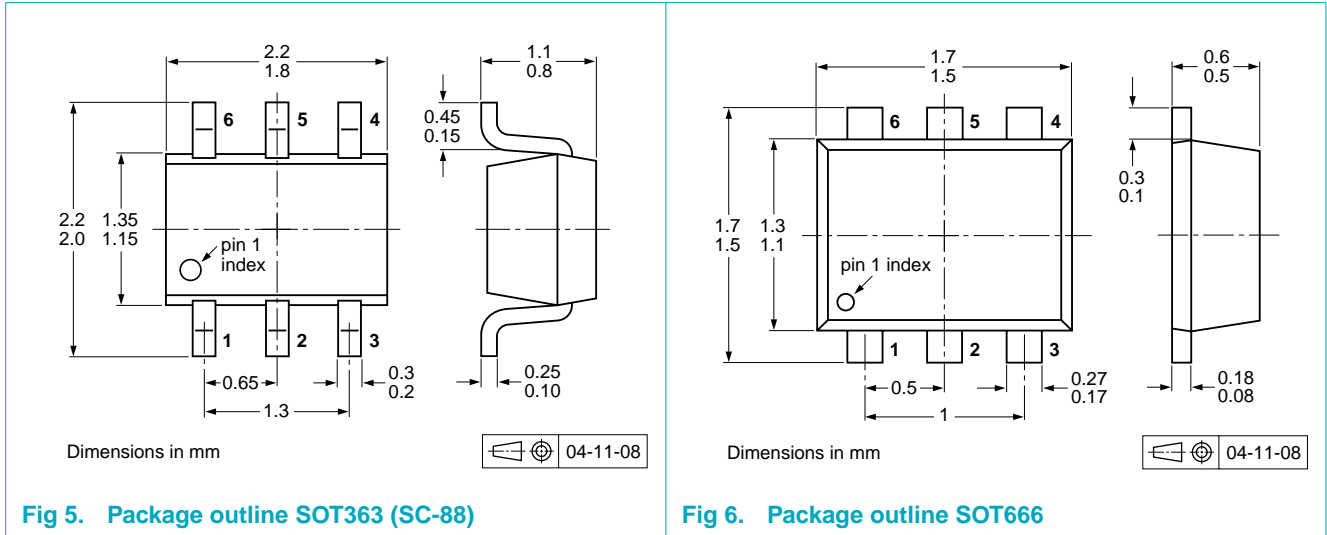


Fig 5. Package outline SOT363 (SC-88)

Fig 6. Package outline SOT666

9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.^[1]

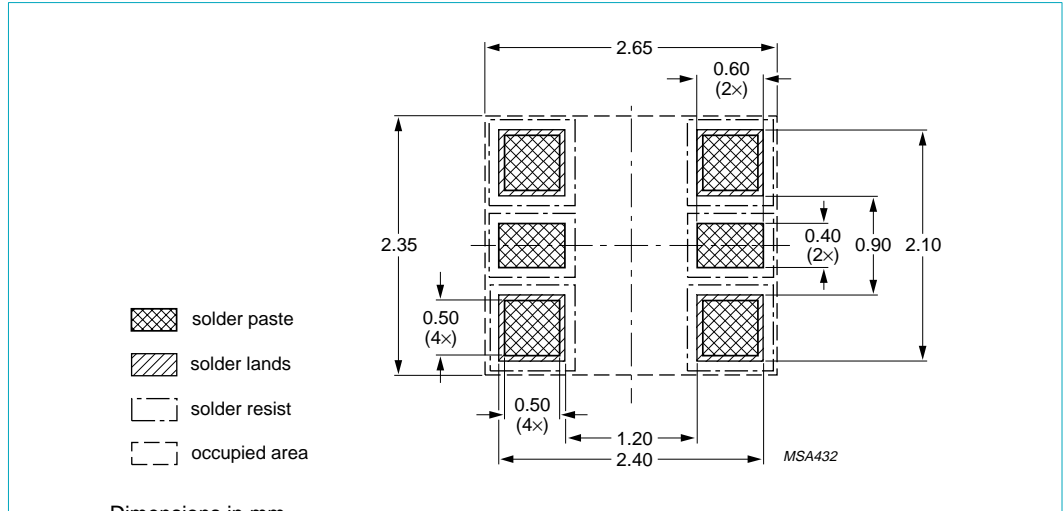
| Type number | Package | Description | Packing quantity | | | |
|-------------|---------|---|------------------|------|------|-------|
| | | | 3000 | 4000 | 8000 | 10000 |
| PEMD30 | SOT666 | 2 mm pitch, 8 mm tape and reel | - | - | -315 | - |
| | | 4 mm pitch, 8 mm tape and reel | - | -115 | - | - |
| PUMD30 | SOT363 | 4 mm pitch, 8 mm tape and reel; T1 ^[2] | -115 | - | - | -135 |
| | | 4 mm pitch, 8 mm tape and reel; T2 ^[3] | -125 | - | - | -165 |

[1] For further information and the availability of packing methods, see [Section 13](#).

[2] T1: normal taping

[3] T2: reverse taping

10. Soldering



Dimensions in mm

Fig 7. Reflow soldering footprint SOT363 (SC-88)

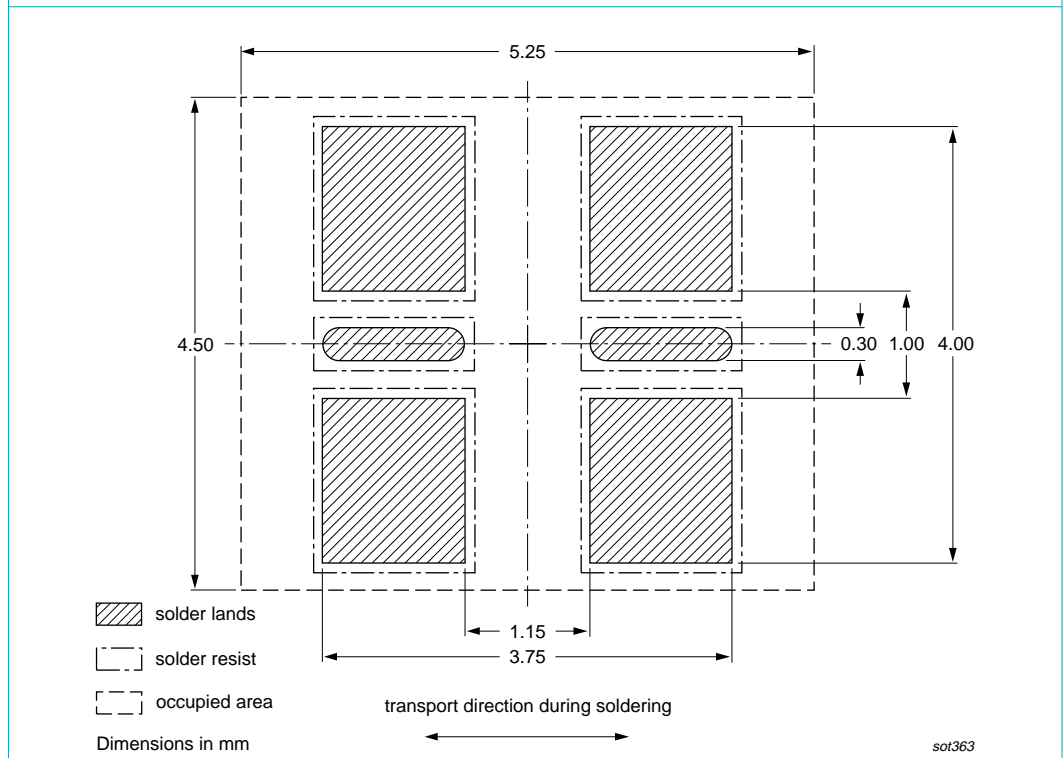
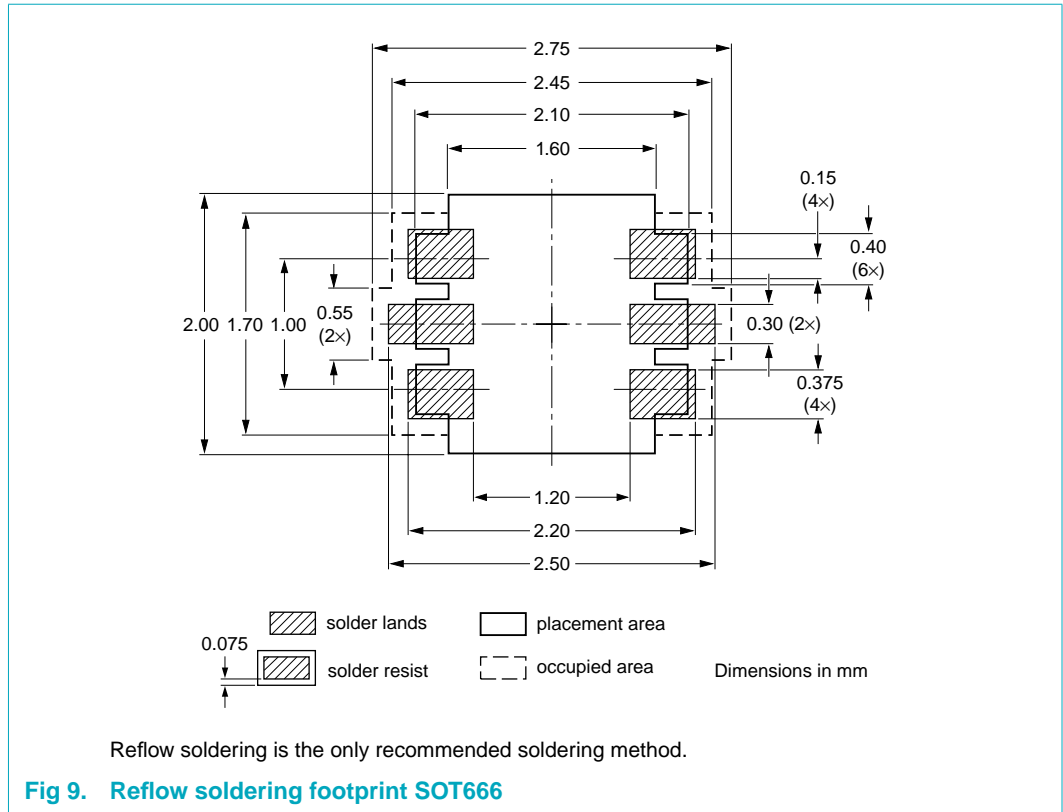


Fig 8. Wave soldering footprint SOT363 (SC-88)



11. Revision history

Table 10. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-----------------|--------------|--------------------|---------------|------------|
| PEMD30_PUMD30_1 | 20060331 | Product data sheet | - | - |

12. Legal information

12.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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